

Vishay Semiconductors

Small Signal Fast Switching Diodes



FEATURES

- Silicon epitaxial planar diode
- Low forward voltage drop
- AEC-Q101 qualified
- · High forward current capability
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



(e2)

COMPLIANT HALOGEN FREE

APPLICATIONS

 High speed switch and general purpose use in computer and industrial applications

DESIGN SUPPORT TOOLS click logo to get started



MECHANICAL DATA

Case: DO-35 (DO-204AH)
Weight: approx. 125 mg
Cathode band color: black
Packaging codes / options:

TR/10K per 13" reel (52 mm tape), 50K/box
TAP/10K per ammopack (52 mm tape), 50K/box

PARTS TABLE PART ORDERING CODE TYPE MARKING CIRCUIT CONFIGURATION REMARKS 1N4150 1N4150TR or 1N4150TAP 1N4150 Single Tape and reel / ammopack

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
Repetitive peak reverse voltage		V_{RRM}	50	V				
Reverse voltage		V_R	50	V				
Peak forward surge current	t _p = 1 μs	I _{FSM}	4	Α				
Average peak forward current		I _{FRM}	600	mA				
Forward continuous current		I _F	300	mA				
Average forward current	V _R = 0	I _{F(AV)}	150	mA				
Power dissipation	I = 4 mm, T _L = 45 °C	P _{tot}	440	mW				
	$I = 4$ mm, $T_L \le 25$ °C	P _{tot}	500	mW				

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Thermal resistance junction to ambient air	I = 4 mm, T _L = constant	R _{thJA}	350	K/W			
Junction temperature		Tj	175	°C			
Storage temperature range		T _{stg}	-65 to +175	°C			



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Forward voltage	I _F = 1 mA	V _F	0.540		0.620	V		
	I _F = 10 mA	V _F	0.660		0.740	V		
	I _F = 50 mA	V_{F}	0.760		0.860	V		
	I _F = 100 mA	V_{F}	0.820		0.920	V		
	I _F = 200 mA	V_{F}	0.870		1	V		
Reverse current	V _R = 50 V	I _R			100	nA		
	V _R = 50 V, T _j = 150 °C	I _R			100	μΑ		
Diode capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $V_{HF} = 50 \text{ mV}$	C _D			2.5	pF		
Reverse recovery time	$I_F = I_R = (10 \text{ to } 100) \text{ mA},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			4	ns		

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

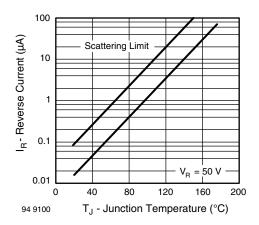


Fig. 1 - Reverse Current vs. Junction Temperature

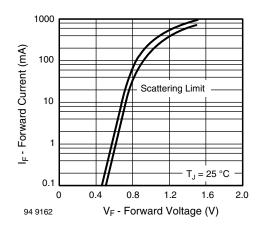
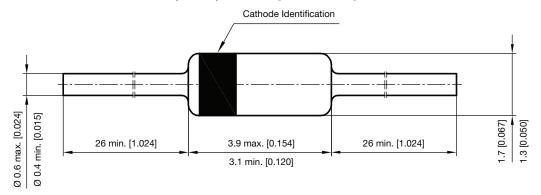


Fig. 2 - Forward Current vs. Forward Voltage

PACKAGE DIMENSIONS in millimeters (inches): DO-35 (DO-204AH)



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1N4150\F3 1N4150TAP 1N4150TR